

High Voltage Green-Mode PWM Controller with BNO Function

REV. 00

General Description

The LD5760E is a Green Mode PWM IC built-in with brown-in/ out functions in a SOP-7 or SOP-8 package. It minimizes the component counts, circuit space, and reduces the overall material cost for the power applications.

The LD5760E features HV start, green-mode power-saving operation, and internal slope compensation, soft-start functions to minimize the power loss and enhance the system performance.

With complete protection in it, as OLP (Over Load Protection), OVP (Over Voltage Protection), fast SCP (short circuit protection) and brown-in/out protection, LD5760E prevents the circuit from being damaged under abnormal conditions.

Furthermore, the LD5760E features frequency swapping and soft driving function to reduce the noise and improve EMI.

Features

- High-Voltage (650V) Startup Circuit
- Built-in Brown-in/out Function on HV pin
- Built- in X-Cap Discharge on HV pin
- Frequency Swapping for EMI improvement
- Non-Audible-Noise Green Mode Control
- LEB (Leading-Edge Blanking) on CS Pin
- Internal Slope Compensation
- Internal OCP Compensation
- OVP (Over Voltage Protection) on VCC/CS
- OLP (Over Load Protection)
- OTP (Over Temperature Protection)
- SCP(Short Circuit Protection)
- Soft Start
- Soft Driving
- +300mA/-800mA Driving Capability

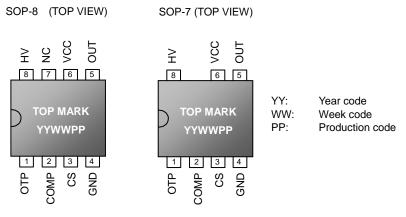
Applications

- Switching AC/DC Adaptor and Battery Charger
- Open Frame Switching Power Supply
- LCD Monitor/TV Power

Typical Application AC EMI Filter OTP LD5760E GND COMP CS



Pin Configuration



Ordering Information

Part number	Package	Top Mark	Shipping
LD5760E GS	SOP-8	LD5760EGS	2500 /tape & reel
LD5760E GR	SOP-7	LD5760EGR	2500 /tape & reel

The LD5760E is ROHS compliant/Green Packaged.

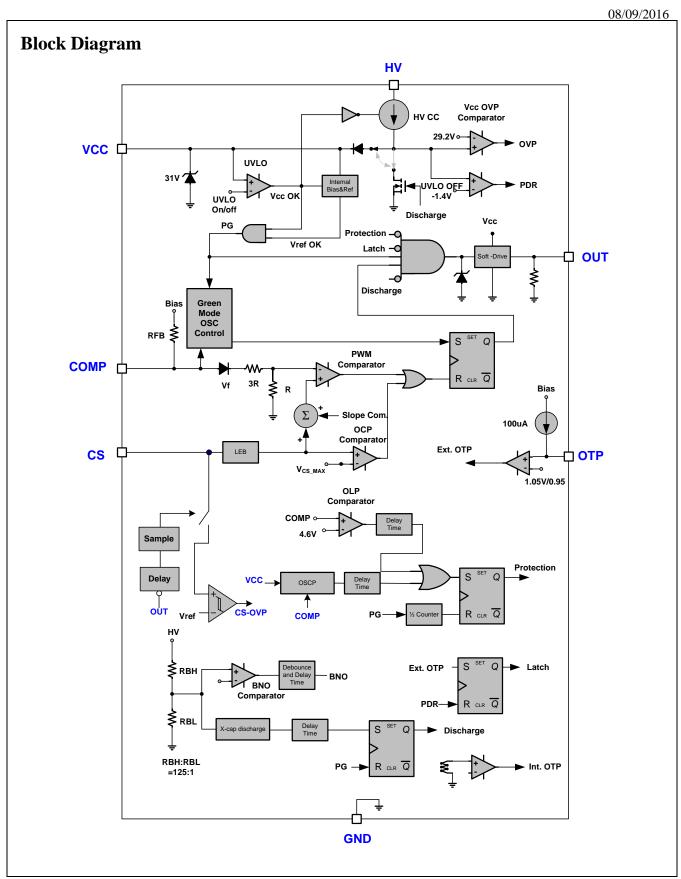
Protection Mode

Part number	VCC_OVP	OSCP	CS_OVP	OLP	ОТР
LD5760E	Auto-Restart	Auto-Restart	Auto-Restart	Auto-Restart	Auto-Restart

Pin Descriptions

PIN	NAME	FUNCTION			
1	ОТР	Pulling this pin below 0.95V will force the controller enter into auto mode and it will shut down the gate output and stop switching of the power MOSFET until the next UVLO(_{ON}). Connect a NTC between this pin and ground to achieve OTP protection function. Let this pin float to disable the latch protection.			
2	COMP	Voltage feedback pin. Connect a photo-coupler with it to close the control loop and achieve the regulation.			
3	CS	Current sense pin, connect it to sense the MOSFET current			
4	GND	Ground			
5	OUT	Gate drive output to drive the external MOSFET			
6	VCC	Supply voltage pin			
7	NC	Unconnected Pin			
8	HV	Connect this pin to Line/ Neutral of AC main voltage through a resistor to provide the startup current for the controller. If VCC voltage increase to trip the point of UVLO(on), this HV loop will be turned off to reduce the power loss on the startup circuit. An internal resistor divider between HV to GND pin will monitor AC line voltage to activate Brown-in/out function.			











Absolute Maximum Ratings

Supply Voltage VCC	-0.3V ~ 30V
HV	-0.3V ~ 650V
COMP, OTP, CS	-0.3V ~ 6V
OUT	-0.3V ~ VCC+0.3V
Maximum Junction Temperature	150°C
Storage Temperature Range	-65°C ~ 150°C
Package Thermal Resistance (SOP-8/SOP-7, θ_{JA})	160°C/W
Power Dissipation (SOP-8/SOP-7, at Ambient Temperature = 85°C)	250mW
Lead temperature (Soldering, 10sec)	260°C
ESD Voltage Protection, Human Body Model (except HV Pin)	2.5KV
ESD Voltage Protection, Machine Model (except HV Pin)	250V
ESD Voltage Protection, Human Body Model (HV Pin)	1KV
ESD Voltage Protection, Machine Model (HV pin)	200V
Gate Output Current	+300mA/-800mA

Caution:

Stress exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stress above Recommended Operating Conditions may affect device reliability.

Recommended Operating Conditions

Item	Min.	Max.	Unit
Operating Junction Temperature	-40	125	°C
Supply VCC Voltage	8.5	26.5	V
HV resistor Value (AC Side)	8	12.5	ΚΩ
HV to GND Capacitor Value		300	pF
COMP Pin Capacitor	1	10	nF
CS Pin Capacitor Value	47	390	pF
OTP Pin Capacitor Value	2.2	10	nF





Electrical Characteristics

 $(T_A = +25^{\circ}C \text{ unless otherwise stated, VCC=15.0V})$

PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNITS
High-Voltage Supply (HV Pin)						
High-Voltage Current Source	VCC< V _{CC_ON} , HV=500V	I _{HV}	2	2.8	3.6	mA
HV Discharge capability	HV=500V	I _{HV_DIS}	2	2.5	3	mA
HV Pin Total Input Current	$VCC > V_{CC_ON}$, $HV=500 V_{DC}$	I _{HV_LEAK}			35	μА
HV Pin Brown-In Level		V _{HVBO}	75	85	95	V_{DC}
HV Pin Brown-out Level		V _{HVBI}	64	72	80	V_{DC}
HV Pin BNO Hysteresis	V _{HVBI} - V _{HVBO}	ΔV_{HV}		13		V_{DC}
Brown-in De-bounce Time	V _{COMP} > V _{ZDCH}	T _{D_HVBI}	100	170	240	μS
Brown-out Detection Delay time		T_{D_HVBO}	54	68	85	mS
HV Pin Min. Operation Voltage	*	V _{HV_MIN}	45			V
X-Cap discharge Detection Delay time	V _{COMP} > V _{ZDCH}	$T_{D_{\!-\!XCAP}}$	54	68	85	mS
Supply Voltage (VCC Pin)						
Startup Current	HV=500V	I _{CC_ST}			50	μА
On a ratio a Commant	V _{COMP} =3V	I _{CC_OP1}	1.4	1.9	2.5	mA
Operating Current (with 1nF load on OUT pin)	V _{COMP} =0V	I _{CC_OP2}	0.2	0.3	0.4	mA
(with the load on OOT pin)	Auto recover mode	I _{CC_OPA}	0.35	0.43	0.55	mA
UVLO(OFF)		V _{CC_OFF}	6	7	8	V
UVLO(ON)		V _{CC_ON}	15	16	17	V
PDR		V _{CC_PDR}		V _{CC_OFF}		V
VCC HVBI Level	HV> V _{HVBI} (Fig. 1)	V _{СС_НУВІ}		V _{CC_OFF} +3.8V		V
VCC OVP Level		V _{CC_OVP}	27.9	29.2	30.5	V
VCC OVP De-bounce Time	*	T _{D_VCCOVP}		80		μS





PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNITS
Oscillator for Switching Fre	equency					
Frequency		F _{SW}	60	65	70	kHz
Swapping Frequency	*	F _{SW_SWA}	±6	±8	±10	%
Green Mode Frequency		F _{SW_GREEN}	20	23	26	kHz
Modulation Frequency	*	F _{SW_MOD}	100	200	300	Hz
F _{SW} Temp. Stability	*, -40°C ~105°C	F _{SW_TS}	0	3	4	%
F _{SW} Voltage Stability	*	F _{SW_VS}	0		1	%
Maximum On Time		MXD	78	85	90	%
OSCP (Output Short Circuit	t Protection)					
OSCP Trip Level	*	V _{CC_OSCP}		V _{CC-OFF} +3.8V		V
OSCP Delay Time	*, Exclude soft start time.	T_{D_OSCP}		15		ms
Voltage Feedback (COMP F	Pin)					
Input Voltage to Current-Sense Attenuation	*	A_V		1/4		V/V
Comp Impedance	V _{COMP} =3V	Z _{COMP}		42		kΩ
Open Loop Voltage		V _{COMP_OPEN}	4.9	5.2	5.5	V
OLP Tripped Level		V_{OLP}	4.4	4.6	4.8	V
PWM Mode Threshold VCOMP	F _{SW_SW} X 0.9 (Fig. 2)	V_{P}	2.6	2.8	3.0	V
Green Mode Threshold VCOMP	F _{SW_GREEN} X1.1 (Fig. 2)	V_{G}	2.3	2.5	2.7	V
Zero Duty Threshold	Zero Duty	V_{ZDC}		1.60		V
VCOMP on Burst mode	Hysteresis	V_{ZDCH}		120		mV
Current Sensing (CS Pin)						
Maximum Input Voltage		V _{CS_MAX}	0.67	0.7	0.73	V
Leading Edge Blanking Time		T _{LEB}	200	300	400	nS
Delay to Output		T_{PD}	30	70	110	nS
Slope Compensation Level	*, 0%-85% Linearly	V _{SLP_L}	0	-	0.2	V
Slope Compensation Position	*, 0%-85% Linearly	VSLP	0		85	%



PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNITS
OVP CS Pin						
OVD Tris Oversont I seed	DC	V _{CSOVP-1}	0.18	0.2	0.22	V
OVP Trip Current Level	AC(High to Low)	V _{CSOVP-2}	0.144	0.164	0.183	V
De-bounce Cycle	*	T_{D_CSOVP}		160		μS
Gate Drive Output (OUT Pin)					
Output Low Level	VCC=15V, Io=20mA	V_{OL}	0	-	1	V
Output High Level	VCC=15V, Io=20mA	V_{OH}	8	-	VCC	V
Rising Time	Load Capacitance= 1000pF	Tr	30	50	70	nS
Falling Time	Load Capacitance= 1000pF	T_f	10	20	30	nS
OUT Pin Clamping Voltage	VCC= 21V,1nF on OUT pin	V _{O_CLAMP}	11	12	13	V
OLP (Over Load Protection)						
OLP Delay Time		T_{D_OLP}	54	66	85	mS
Soft Start						
Soft Start Duration	*	T _{SS}		7		mS
Internal OTP						
OTP Tripped Level	*	T _{INOTP}		140		°C
OTP Hysteresis	*	T _{INOTP_HYS}		T _{OTP} -30		°C
Over Temperature Protection(OTP Pin)						
OTP Pin Source Current		I _{OTP}	92	100	108	μΑ
Turn-On Trip Level		V_{OTP_ON}	1.00	1.05	1.10	V
Turn-Off Trip Level		V_{OTP_OFF}	0.9	0.95	1.0	V
OTP pin de-bounce time	$V_{COMP} > V_{ZDCH}$	T_{D_OTP}	80	140	200	μS

^{*:} Guaranteed by design.

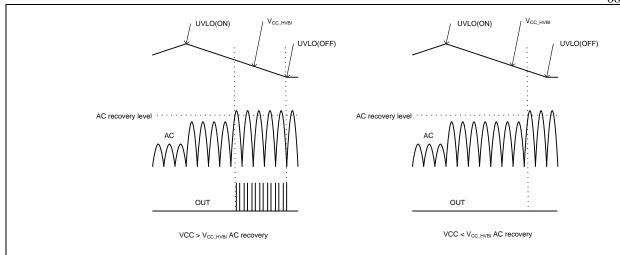
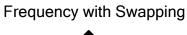


Fig. 1 V_{CC_HVBI} & AC recovery



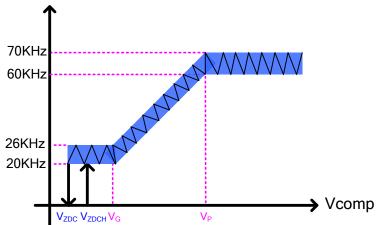
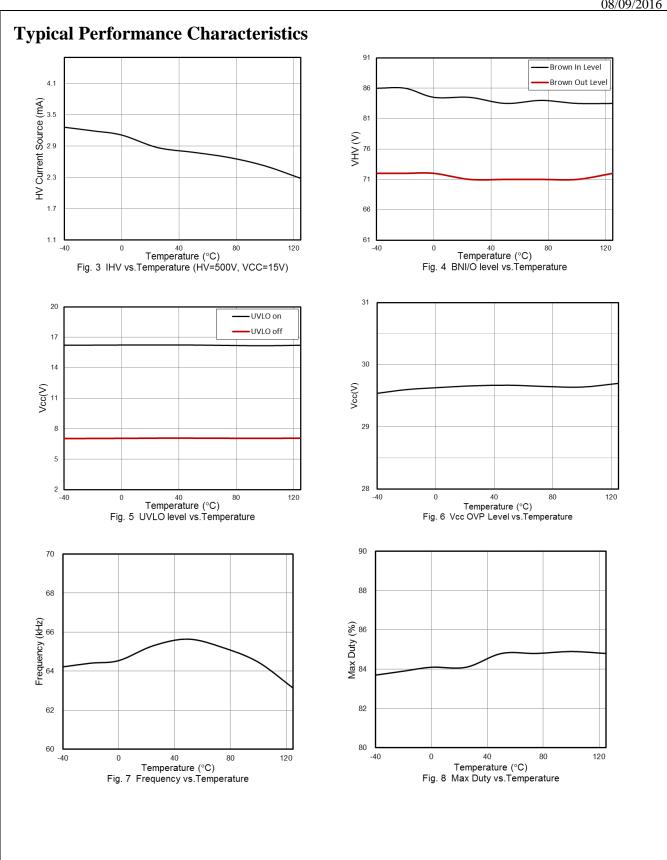


Fig. 2 V_{COMP} vs. PWM Frequency

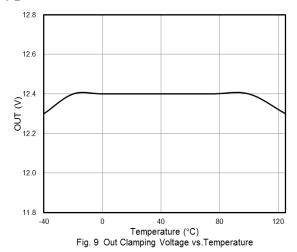








Typical Performance Characteristics



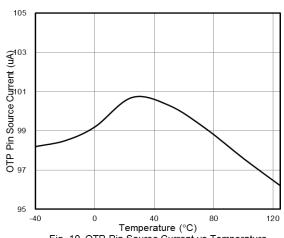


Fig. 10 OTP Pin Source Current vs.Temperature



Application Information

Operation Overview

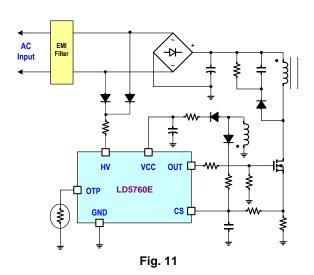
As long as the requirement for green power becomes a trend and the power saving is getting more and more important for the switching power supplies and switching adaptors, the traditional PWM controllers are not able to support such new requirements. Due to the cost and size limit, the PWM controller designer is bound to integrate with more functions to reduce the external part counts. The LD5760E is ideal for these applications. Its detailed features are described as below.

Internal High-Voltage Startup Circuit and Under Voltage Lockout (UVLO)

The traditional circuit provides the startup current through a startup resistor to power up the PWM controller. However, it consumes much significant power to meet the current power saving requirement. In most cases, startup resistors carry larger resistance and spend more time to start up.

To achieve the optimized topology, as shown in Fig. 11, LD5760E is implemented with a high-voltage startup circuit for such requirement. At startup, the high-voltage current source sinks current of AC Line/or Neutral to provide startup current and charge the capacitor C1 connected to VCC.

At the startup transient, the HV current will supply around 2.8mA to Vcc capacitor until this VCC voltage reaches the UVLO threshold VCC. By using such configuration, the turn-on delay time will be almost same no matter under low-line or high-line conditions.



As VCC trips UVLO(OFF), HV pin will recharge VCC capacitor till VCC voltage rises back to UVLO(ON) again. Since then, HV pin would no longer charge the capacitor and instead, send a gate drive signal to draw supply current for VCC from the auxiliary winding of the transformer. That minimizes the power loss on the start-up circuit successfully.

An UVLO comparator is embedded to detect the voltage across the VCC pin to ensure the supply voltage enough to power on the LD5760E and in addition, to drive the power MOSFET. As shown in Fig. 12, a hysteresis is provided to prevent shutdown from the voltage dip during startup. The turn-on and turn-off threshold level are set at 16V and 7V, respectively.

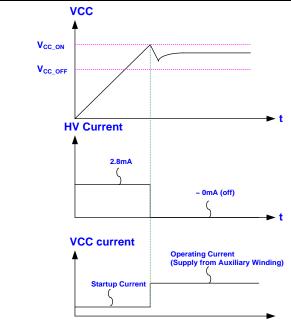


Fig. 12

Brown in/out Protection

The LD5760E features Burn-in/out function on HV pin. As the built-in comparator detects the half wave rectify line voltage condition, it will shut off the controller to prevent from any damage. Fig. 13 shows the operation. When $V_{HV} <$ HVBO, the gate output will remain off even when the VCC already reaches UVLO(ON). It therefore forces the VCC hiccup between UVLO(ON) and UVLO(OFF). Unless the line voltage rises over HVBI V_{AC} , the gate output will not start switching even as the next UVLO(ON) is tripped. A hysteresis is implemented to prevent the false-triggering during turn-on and turn-off.

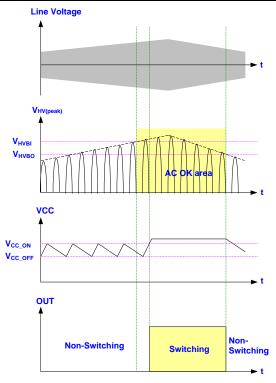


Fig. 13

Current Sensing, Leading-Edge Blanking and the Negative Spike on CS Pin

The typical current mode PWM controller feedbacks both current signal and voltage signal to close the control loop and achieve regulation. The LD5760E detects the primary MOSFET current across CS pin to control in peak current mode and also limit the pulse-by-pulse current. The maximum voltage threshold of the current sensing pin is set at 0.7V. Thus the MOSFET peak current can be calculated as:

$$I_{PEAK (MAX)} = \frac{0.7V}{R_S}$$

A 300nS leading-edge blanking (LEB) time is designed in the input of CS pin to prevent false-triggering from the current spike. In the low power applications, if the total pulse width of the turn-on spikes is less than 150nS and the negative spike on the CS pin does not exceed -0.3V, the R-C filter (as shown in Fig. 14) is free to eliminate.

However, the total pulse width of the turn-on spike is related to the output power, circuit design and PCB



layout. It is strongly recommended to add a small R-C filter (as shown in Fig. 15) for larger power application to avoid the CS pin from being damaged by the negative turn-on spike.

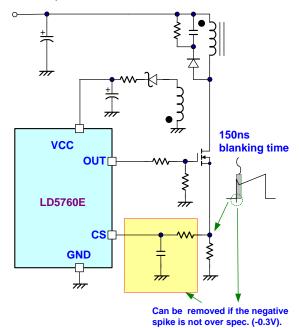


Fig. 14

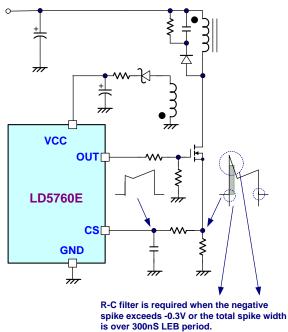


Fig. 15

Output Stage and Maximum Duty-Cycle

A CMOS buffer with output stage of typical 300mA driving capability is incorporated to drive a power MOSFET directly. And the maximum duty-cycle of LD5760E is limited to 85% to avoid the transformer saturation.

Voltage Feedback Loop

The voltage feedback signal is provided from the TL431 on the secondary side through the photo-coupler to the COMP pin of LD5760E. Similar to UC384X, its input stage is with a diode voltage offset to feed the voltage divider with 1/4 ratio, that is,

$$V_{CS(PWM_{COMPARATOR})} = \frac{1}{4} \times (V_{COMP} - V_F)$$

A pull-high resistor is embedded internally to optimize the external circuit.

Internal Slope Compensation

A fundamental issue of current mode control is the stability problem when its duty-cycle is operated for more than 50%. To stabilize the control loop, the slope compensation is required in the traditional UC384X design by injecting the ramp signal from the RT/CT pin through a coupling capacitor. LD5760E has internal slope compensation circuit to simplify the external circuit design.

Oscillator and Switching Frequency

The LD5760E fixes the switching frequency at 65kHz internally to optimize its performance in EMI, thermal treatment, component sizes and transformer design.

Dual-Oscillator Green-Mode Operation

There are many different topologies has been implemented in different chips for the green-mode or power saving requirements such as "burst-mode control", "skipping-cycle mode", "variable off-time control "...etc. The basic operation theory of all these approaches intended to reduce the switching cycles under light-load or no-load condition either by skipping





some switching pulses or reduce the switching frequency.

By using LD proprietary dual-oscillator technique, the green-mode frequency can be well controlled and further to avoid the generation of audible noise.

Frequency Swapping

The LD5760E is built in with frequency swapping function, which makes it easy for the power supply designers to optimize EMI performance and system cost. The frequency swapping is internally set for $\pm 8\%$.

On/Off Control

Pulling COMP pin below VFB_B will immediately disable the gate output of LD5760E. Remove the pull-low signal to reset it.

Over Load Protection (OLP) - Auto Recovery

To protect the circuit from being damaged during over load condition and short or open loop condition, the LD5760E is implemented with smart OLP function. LD5760E features auto recovery function of it, see Fig. 16 for the waveform. In the example of the fault condition, the feedback system will force the voltage loop enter toward the saturation and then pull the voltage high on COMP pin (VCOMP). As the V_{COMP} ramps up to the OLP tripped level (4.6V) and stays for more than the OLP delay time, the protection will be activated and then turn off the gate output to stop the switching of power circuit. The OLP delay time is set by internal high frequency counter. It is to prevent the false triggering from the power-on and turn-off transient.

A divide-2 counter is implemented to reduce the average power under OLP behavior. As soon as OLP is activated, the output will be latched off and the divide-2 counter will start to count the number of UVLO(OFF). The latch will not be released until the 2rd UVLO(OFF) point is counted, after that the output will resume to switch again. With the protection

mechanism, the average input power will be minimized, so that the component temperature and stress can be controlled within the safe operating area.

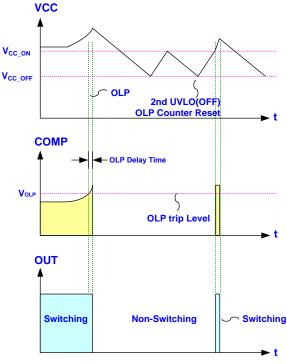


Fig. 16

OVP (Over Voltage Protection) on VCC – Auto Recovery

The V_{GS} ratings of the nowadays power MOSFETs are mostly with 30.5V maximum. To protect the V_{GS} from the fault condition, LD5761 is implemented with OVP function on VCC. As the VCC voltage is larger than the OVP threshold voltage, it will shut off the output gate drive circuit simultaneously and the switching of the power MOSFET is disabled until the 2rd UVLO(OFF) point is counted.

The Vcc OVP functions of LD5760E are auto-recoverable. If the OVP condition, usually caused by open-loop of feedback, is not released, the Vcc will tripped the OVP level again and re-shutdown the output. The Vcc works in hiccup mode. Figure 17 shows its operation.

Otherwise, when the OVP condition is removed, the Vcc level will be resumed and the output will automatically return to the normal operation.

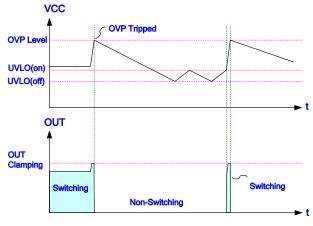


Fig. 17

On-Chip OTP - Auto Recovery

An internal OTP circuit is embedded inside the LD5760E to provide the worst-case protection for this controller. When the chip temperature rises higher than the trip OTP level, the output will be disabled until the chip is cooled down below the hysteresis window.

External OTP - Auto Recovery

The OTP circuit is implemented to sense whether there is any hot-spot of power circuit like power MOSFET or output rectifier. Typically, an NTC is recommended to connect with OTP pin. The NTC resistance will decrease as the device or ambient is in high temperature. The relationship is described as below.

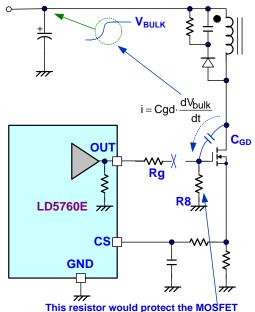
$$V_{OTP} = 100 \mu A \cdot R_{NTC}$$

When the V_{OTP} is below the defined voltage threshold (typ. 0.95V), LD5760E will shut down the gate output and stop switching of the power MOSFET until the 2rd UVLO(OFF) point is counted.

Pull-Low Resistor on the Gate Pin of MOSFET

The LD5760E consists of an anti-floating resistor with OUT pin to protect the output from damage in abnormally operation or condition due to false triggering of MOSFET. Even so, we still recommend adding an external one at the MOSFET gate terminal to provide more protection in case of disconnection of gate resistor $R_{\rm G}$ during power-on.

In such single-fault condition, as shown in Fig. 18, the resistor R8 can provide a discharge path to avoid the MOSFET from being false-triggered by the current through the gate-to-drain capacitor C_{GD} . Therefore, the MOSFET should be always pulled low and placed in the off-state as the gate resistor is disconnected or opened in any case.



This resistor would protect the MOSFET from being false triggered by the current through C_{GD} , if R_{G} is disconnected.

Fig. 18

Protection Resistor on the Hi-V Path

In some other Hi-V process and design, there may be a parasitic SCR caused around HV pin, Vcc and GND. As shown in Fig. 19, a small negative spike on the HV pin may trigger this parasitic SCR and cause latch-up



between VCC and GND. It may damage the chip because of the equivalent short-circuit induced by such latch-up behavior.

Leadtrend's proprietary of Hi-V technology will eliminate parasitic SCR in LD5760E. Fig. 20 shows the equivalent Hi-V structure circuit of LD5760E. So that LD5760E is more capable to sustain negative voltage than similar products. However, a $10 \mathrm{K}\Omega$ resistor is recommended to add in the Hi-V path to play as a current limit resistor as a negative voltage is applied.

Negative-triggered Parasitic SCR. Small negative spike on HV pin will cause the latchup between VCC and GND.

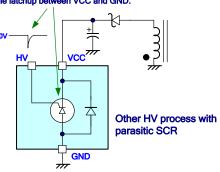


Fig. 19

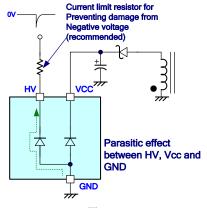


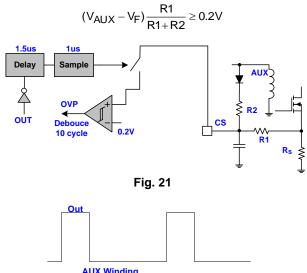
Fig. 20

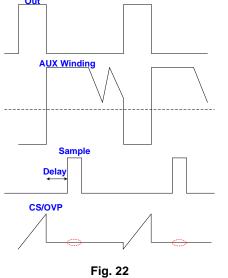
Over Voltage Protection (OVP) on CS pin - Auto Recovery

An output overvoltage protection is implemented in the LD5760E, as shown in Fig. 21 and 22. The auxiliary winding voltage is reflected to secondary winding and

therefore the flat voltage on the CS pin is proportional to the output voltage. By sensing the auxiliary voltage via the divided resistors, LD5760E can sample this flat voltage level after some delay time to perform output over-voltage protection. This delay time is used to ignore the voltage ringing from leakage inductance of PWM transformer. The sampling voltage level is compared with internal threshold voltage 0.2V. If the sampling voltage exceeds the OVP trip level, an internal counter starts counting subsequent OVP events. The counter has been added to prevent incorrect OVP detection which might occur during ESD or lightning events. However, if typically 10 cycles of subsequent OVP events are detected, the OVP circuit switches the power MOSFET off.

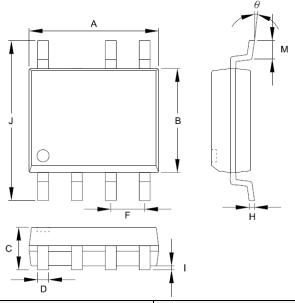
Thus the output over voltage can be calculated as:







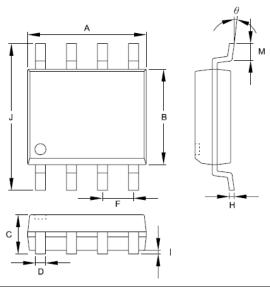
Package Information SOP-7



	Dimensions i	Dimensions in Millimeters		ns in Inch
Symbols	MIN	MAX	MIN	MAX
А	4.801	5.004	0.189	0.197
В	3.810	3.988	0.150	0.157
С	1.346	1.753	0.053	0.069
D	0.330	0.508	0.013	0.020
F	1.194	1.346	0.047	0.053
Н	0.178	0.254	0.007	0.010
I	0.102	0.254	0.004	0.010
J	5.791	6.198	0.228	0.244
М	0.406	1.270	0.016	0.050
θ	0°	8°	0°	8°



SOP-8



	Dimensions i	Dimensions in Millimeters		ns in Inch
Symbols	MIN	MAX	MIN	MAX
А	4.801	5.004	0.189	0.197
В	3.810	3.988	0.150	0.157
С	1.346	1.753	0.053	0.069
D	0.330	0.508	0.013	0.020
F	1.194	1.346	0.047	0.053
Н	0.178	0.254	0.007	0.010
I	0.102	0.254	0.004	0.010
J	5.791	6.198	0.228	0.244
М	0.406	1.270	0.016	0.050
θ	0°	8°	0°	8°

Important Notice

Leadtrend Technology Corp. reserves the right to make changes or corrections to its products at any time without notice. Customers should verify the datasheets are current and complete before placing order.





Revision History

REV.	Date	Change Notice
00	08/09/2016	Original Specification.